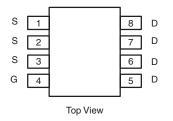


Vishay Siliconix

P-Channel 1.8-V (G-S) MOSFET

PRODUCT SUMMARY				
V _{DS} (V)	R_{DS(on)} (Ω)	I _D (A)		
- 20	0.017 at V _{GS} = - 4.5 V	- 9.9		
	0.023 at V _{GS} = - 2.5 V	- 8.5		
	0.032 at V _{GS} = - 1.8 V	- 7.2		

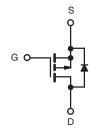




FEATURES

- Halogen-free According to IEC 61249-2-21
 Definition
- TrenchFET[®] Power MOSFETs
- Compliant to RoHS Directive 2002/95/EC





P-Channel MOSFET

Ordering Information: Si4403BDY-T1-E3 (Lead (Pb)-free) Si4403BDY-T1-GE3 (Lead (Pb)-free and Halogen-free)

ABSOLUTE MAXIMUM RATINGS	T _A = 25 °C, unles	ss otherwise n	oted			
Parameter		Symbol	10 s	Steady State	Unit	
Drain-Source Voltage		V _{DS}	- 20		V	
Gate-Source Voltage		V _{GS}	± 8			
Continuous Droin Queront (T 150 °C)	T _A = 25 °C	– I _D	- 9.9	- 7.3		
Continuous Drain Current (T _J = 150 °C) ^a	T _A = 70 °C		- 7.9	- 5.8	^	
Pulsed Drain Current		I _{DM}	- 30		A	
Continuous Source Current (Diode Conduction) ^a		۱ _S	- 2.3	- 1.3		
	T _A = 25 °C	P _D	2.5	1.35	W	
Maximum Power Dissipation ^a	T _A = 70 °C		1.6	0.87	vv	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150		°C	

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
Maximum Junction-to-Ambient ^a	t ≤ 10 s	R _{thJA}	43	50	
Maximum Junction-to-Ambient*	Steady State		71	92	°C/W
Maximum Junction-to-Foot (Drain)	Steady State	R _{thJF}	19	25	

Notes:

a. Surface Mounted on 1" x 1" FR4 board.

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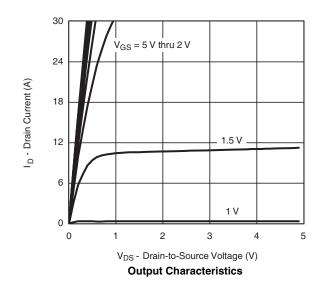


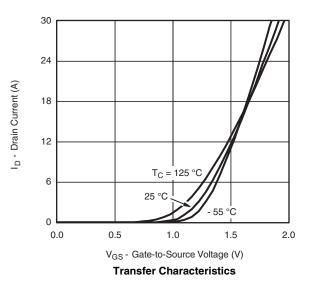
Parameter	Symbol	Test Conditions Min.		Тур.	Max.	Unit	
Static	. <u> </u>						
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}$, $I_D = -350 \ \mu A$	- 0.45		- 1.0	V	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 8 V$			± 100	nA	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = - 20 V, V _{GS} = 0 V			- 1		
		$V_{DS} = -20 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 70 ^{\circ}\text{C}$			- 10	μΑ	
On-State Drain Current ^a	I _{D(on)}	$V_{DS} = -5 V, V_{GS} = -4.5 V$	4.5 V 20			Α	
Drain-Source On-State Resistance ^a	R _{DS(on)}	$V_{GS} = -4.5 \text{ V}, \text{ I}_{D} = -9.9 \text{ A}$		0.014	0.017	Ω	
		$V_{GS} = -2.5 \text{ V}, \text{ I}_{D} = -8.5 \text{ A}$		0.018	0.023		
		V _{GS} = - 1.8 V, I _D = - 3.1 A		0.024	0.032		
Forward Transconductance ^a	9 _{fs}	$V_{DS} = -15 \text{ V}, \text{ I}_{D} = -9.9 \text{ A}$		36		S	
Diode Forward Voltage ^a	V _{SD}	I _S = - 2.3 A, V _{GS} = 0 V		- 0.8	- 1.1	V	
Dynamic ^b							
Total Gate Charge	Qg			33	50		
Gate-Source Charge	Q _{gs}	V_{DS} = - 10 V, V_{GS} = - 5 V, I_{D} = - 9.9 A		4.2		nC	
Gate-Drain Charge	Q _{gd}			7.6		1	
Turn-On Delay Time	t _{d(on)}			25	40		
Rise Time	t _r	V_{DD} = - 10 V, R_L = 15 Ω		45	70	ns	
Turn-Off Delay Time	t _{d(off)}	$\text{I}_\text{D}\cong$ - 1 A, V_GEN = - 4.5 V, R_g = 6 Ω		150	225		
Fall Time	t _f			70	110		
Source-Drain Reverse Recovery Time	t _{rr}	I _F = - 2.3 A, dl/dt = 100 A/μs		40	60		

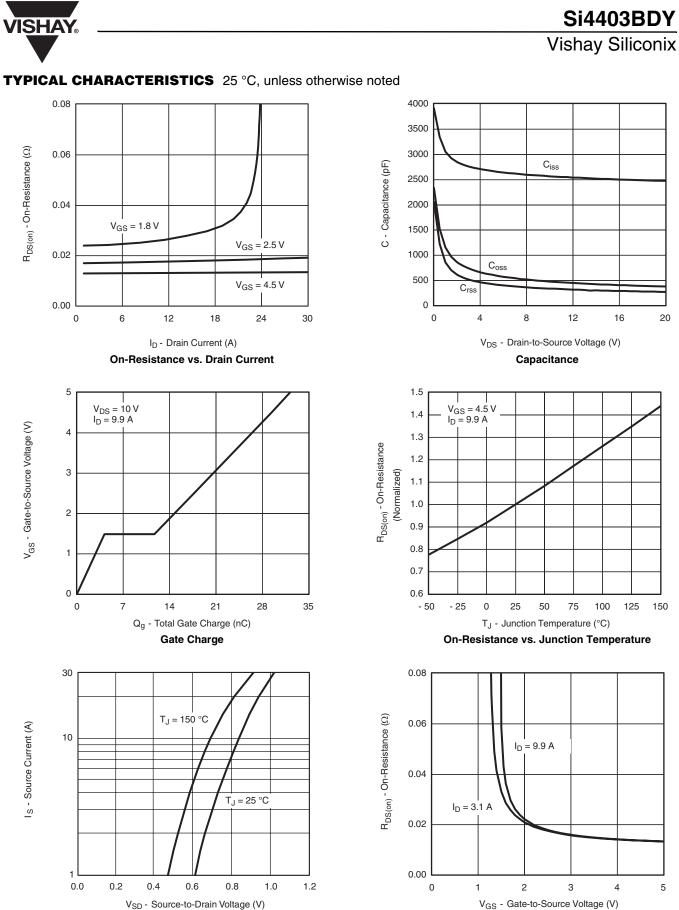
Notes: a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %. b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted







Source-Drain Diode Forward Voltage

Document Number: 72268 S09-0705-Rev. C, 27-Apr-09 On-Resistance vs. Gate-to-Source Voltage

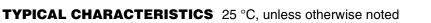
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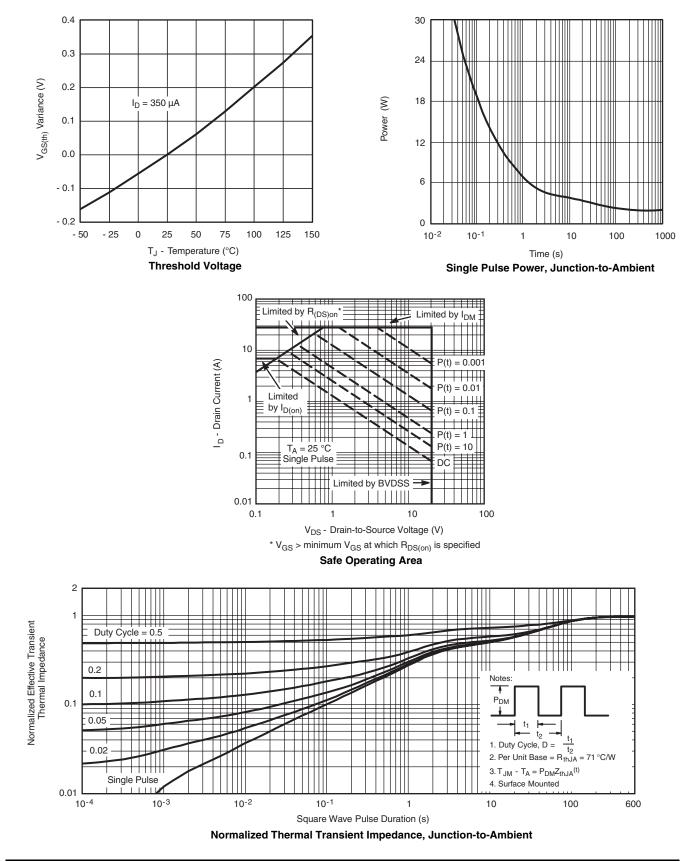
20

150

Si4403BDY

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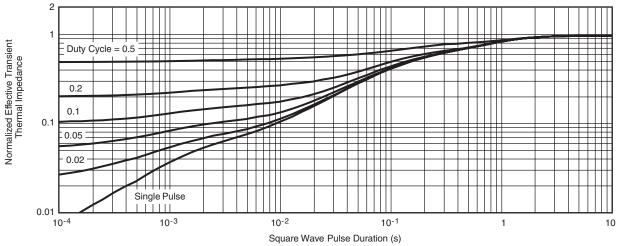




Si4403BDY

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TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Normalized Thermal Transient Impedance, Junction-to-Foot

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg772268.



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